Clock OSC SG5032CCN

Product name SG5032CCN 4.450000 MHz HJGA Product Number / Ordering code X1G0044710065xx

Please refer to the 8.Packing information about xx (last 2 digits)

Output waveform CMOS

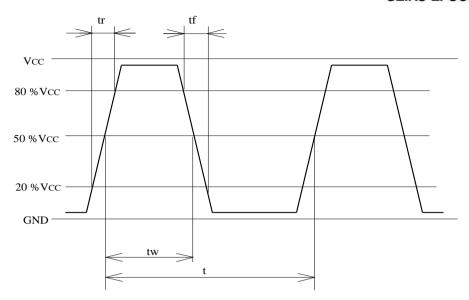
Pb free / Complies with EU RoHS directive

Reference weight Typ. 52 mg

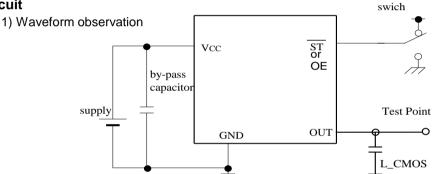
1.Absolute maximum ratings								
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions / Remarks		
Maximum supply voltage	Vcc-GND	-0.3	-	+7	V	-		
Storage temperature	T_stg	-40	-	+125	°C	Storage as single product		
Input voltage	Vin	-0.5	-	Vcc+0.5	V	OE terminal		

2.Specifications(charac	teristics)						
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions / Remarks	
Output frequency	f0		4.450000		MHz		
Supply voltage	Vcc	4.5	5	5.5	V	-	
Operating temperature	T_use	-40	-	+85	۰C	-	
Frequency tolerance	f_tol	-50	-	50	x10 ⁻⁶	T_use	
Current consumption	Icc	-	-	20	mA	No load condition	
Stand-by current	I_std	-	-	-	μΑ	-	
Disable current	I_dis	-	-	10.0	mA	OE = GND	
Symmetry	SYM	40	-	60	%	50% Vcc Level L_CMOS=<50pF	
Output voltage	V _{OH}	Vcc-0.4	-	-		-	
	V_{OL}	=	1	0.4		-	
Output load condition	L_CMOS	-	ı	50	pF	CMOS Load	
Input voltage	V_{IH}	0.8Vcc	ı	-		OE terminal	
	V_{IL}	-	ı	0.2Vcc		OE terminal	
Rise time	t _r	-	-	5	ns	0.2Vcc to 0.8Vcc Level, L_CMOS=50pF	
Fall time	tf	-	-	5	ns	0.2Vcc to 0.8Vcc Level, L_CMOS=50pF	
Start-up time	t_str	-	-	5	ms	t = 0 at 0.9Vcc	
Jitter	t _{DJ}	-	-	-	ps	Deterministic Jitter	
	t _{RJ}	-	-	-	ps	Random Jitter	
	t _{RMS}	-	-	-	ps	σ(RMS of total distribution)	
	t _{p-p}	-	-	-	ps	Peak to Peak	
	t _{acc}	-	-	-	ps	Accumulated Jitter(σ), n = 2 to 50 000 cycles	
Phase jitter	t _{PJ}	-	-	-	ps	Offset Frequency: 12 kHz to 20 MHz	
Phase noise	L(f)	-	-	-	dBc/Hz	Offset 1 Hz	
		-	-	-	dBc/Hz	Offset 10 Hz	
		-	-	-	dBc/Hz	Offset 100 Hz	
		-	-	-	dBc/Hz	Offset 1 kHz	
		-	-	-	dBc/Hz	Offset 10 kHz, Vcc = 3.3 V	
		-	-	-	dBc/Hz	Offset 100 kHz	
		-	-	-	dBc/Hz	Offset 1 MHz	
Frequency aging	f_age	-5	-	5	x10 ⁻⁶	@+25°C first year	
		-	-	-		-	

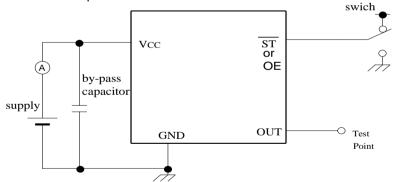
3.Timing chart



4.Test circuit

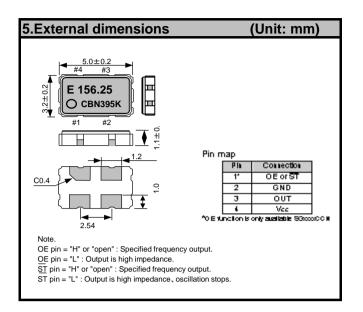


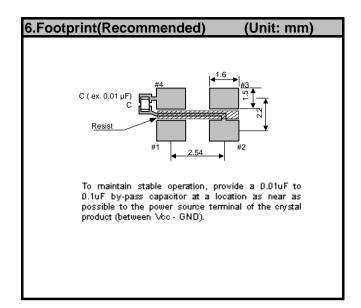
2) Current consumption

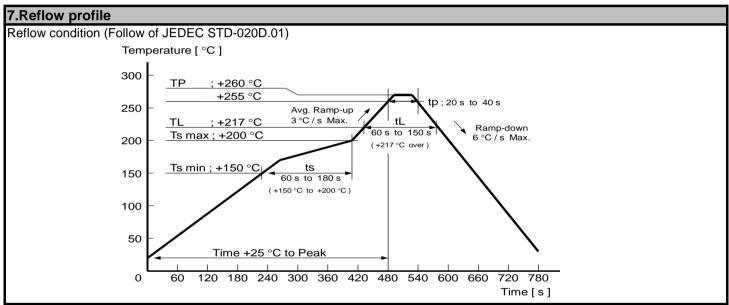


*Current consumption under the disable function should be = GND.

- 3) Condition
- (1) Oscilloscope
- \cdot Band width should be minimum 5 times higher (wider) than measurement frequency.
- · Probe earth should be placed closely from test point and lead length should be as short as possible
- * Recommendable to use miniature socket. (Don't use earth lead.)
- (2) L_CMOS also includes probe capacitance.
- (3) By-pass capacitor (0.01 μF to 0.1 μF) is placed closely between VCC and GND.
- (4) Use the current meter whose internal impedance value is small.
- (5) Power supply
- · Start up time (0 %VCC to 90 %VCC) of power source should be more than 150 µs.
- · Impedance of power supply should be as lowest as possible.







8.Packing	g informa	tion		
[1]Produc	t number l	ast 2 digits code(xx) description		The recommended code is "00"
	X1G0044	1710065xx		
	Code	Condition	Code	Condition
	01	Any Q'ty vinyl bag(Tape cut)	13	500pcs / Reel
	11	Any Q'ty / Reel	00	1000pcs / Reel
	12	250pcs / Reel		

[2] Taping specification Subject to EIA-481 & IEC-60286 (1) Tape dimensions Material of the Carrier Tape: PS Material of the Top Tape : PET+PE Unit: mm User direction of feed 0 0 0 0 0 Carrier tape MARKING Ы Top tape Symbol В С D Ε F G Н 4.0±0.1 7.25±0.2 12.0±0.2 1.40±0.1 3.5±0.1 Value φ1.5 8.0±0.1 5.4±0.1 +0.1/-0 (2) Reel dimensions Center material : PS Material of the Reel: PS 13.0 ± 1.0 \bigcirc ϕ 60 \pm 1 \bigcirc \bigcirc 2 ± 0.2

9.Notice

- · This material is subject to change without notice.
- Any part of this material may not be reproduced or duplicated in any form or any means without the written permission of Seiko Epson.
- The information about applied data, circuitry, software, usage, etc. written in this material is intended for reference only.
 - Seiko Epson does not assume any liability for the occurrence of customer damage or infringing on any patent or copyright of a third party.
 - This material does not authorize the licensing for any patent or intellectual copyrights.
- When exporting the products or technology described in this material, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations.
- You are requested not to use the products (and any technical information furnished, if any) for the development and/or manufacture of weapon of mass destruction or for other military purposes. You are also requested that you
 - would not make the products available to any third party who may use the products for such prohibited purposes.
- These products are intended for general use in electronic equipment. When using them in specific applications that require
 - extremely high reliability, such as the applications stated below, you must obtain permission from Seiko Epson in advance.
 - / Space equipment (artificial satellites, rockets, etc.)
 - / Transportation vehicles and related (automobiles, aircraft, trains, vessels, etc.)
 - / Medical instruments to sustain life
 - / Submarine transmitters
 - / Power stations and related
 - / Fire work equipment and security equipment
 - / Traffic control equipment
 - / And others requiring equivalent reliability.

10.Contact us

www5.epsondevice.com/en/contact/